



A modified high-temperature vapour deposition technique for fabricating $\text{CH}_3\text{NH}_3\text{PbI}_3$ thin films under an ambient atmosphere

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Abstract. A modified two-step deposition technique was performed by vapour depositing methylammonium iodide (MAI) on lead iodide (PbI_2) films to fabricate good quality methylammonium lead iodide (MAPI) thin films under an ambient atmosphere, and their properties were compared with conventional two-step solution processed MAPI thin films. Scanning electron microscopy results depicted that the MAI vapour-processed films have a uniform coverage and planar surface compared with the non-uniformly distributed granule-like morphology of the solution-processed MAPI film. X-ray diffraction results confirm that the vapour-processed films have better crystallinity compared to the conventional solution-processed MAPI thin films. An enhancement in the optical absorption and emission was observed for the vapour-processed films. The higher processing temperature of the modified-vapour deposition eliminates the effect of moisture during the ambient atmosphere processing of the MAPI films.

Keywords. Methylammonium lead iodide; two-step deposition; methylammonium iodide vapour; perovskite solar cells.

1. Introduction

Metal-halide hybrid perovskite solar cells (PSCs) have rapidly evolved as a prevalent and promising technology for efficiently harvesting solar energy. The organic lead halide PSCs are highly vulnerable to moisture and atmospheric oxygen (O_2). Hence, the majority of PSC fabrication is performed in a glove box under an inert atmosphere, where the processing atmosphere constituents are controlled in parts per million. Methylammonium lead iodide ($\text{CH}_3\text{NH}_3\text{PbI}_3$; MAPI) is a well-known and widely investigated compound among the other hybrid PSC materials. Various processing techniques have been investigated for the fabrication of MAPI [1–7]. All the available techniques can be divided into two types: (i) one-step deposition (all the precursors are combined and processed in a single step) and (ii) two-step deposition (sequential deposition of PbI_2 followed by methylammonium iodide ($\text{CH}_3\text{NH}_3\text{I}$; MAI)), which are widely employed for the fabrication of MAPI thin films. These deposition techniques are executed by either solution processing or vapour processing of the precursor materials. Solution processing under an inert atmosphere has proven to be an efficient technique and is adopted in most of the research studies [8]. The vapour processing technique is a mature technology and has been widely used for the large-scale fabrication of organic electronics and semiconductors [7,9]. Vapour processing of MAPI has been executed using both one-step (sequential) and two-step deposition techniques [3,10]. Note that all these processing techniques require a complex instrumental setup to control the processing atmosphere. One of the key drawbacks of PSCs

is that an inert atmosphere or high-vacuum environment is required to process the organic lead halide PSCs, in order to eliminate the effect of moisture and O_2 -induced degradation. Hence, there is a need to identify a processing technique which can be employed to fabricate MAPI-based PSCs in an ambient environment.

Different strategies have been adopted to fabricate high-efficiency PSCs under ambient air. Wang *et al* [11] demonstrated a power conversion efficiency (PCE) of 12.98% with the PSCs fabricated under >50% relative humidity (RH). They employed vacuum annealing of the one-step spin coated films to enhance the film quality. By using ethylene glycol as an anti-solvent, Troughton *et al* [12] fabricated PSCs exhibiting PCEs up to 15% under 75% RH. Surface modification of MAPI by the addition of hydrophobic 4-*tert*-butylpyridine showed enhanced stability for the PSCs at even >75% RH in ambient air [13]. A composite-based interface engineered PSCs including a $\text{Al}_2\text{O}_3/\text{NiO}_2$ interface in the PSC device configuration showed a high PCE of 18.14% and long-term stability under an ambient atmosphere [14]. Air-assisted flow annealed MAPI film-based PSCs showed a promising efficiency of 13.28% under ambient air [15]. Recently, Wu *et al* [16] demonstrated 16% PCE under ambient air conditions (25% RH) by adding *n*-butylamine as an additive to enhance the quality of PbI_2 and thus achieve a high-quality perovskite layer.

It is well known that the effect of moisture leads to poor quality of the MAPI thin films and ultimately affects the device performance. This limits the large scale manufacturing of MAPI-based solar modules. In the present work, a

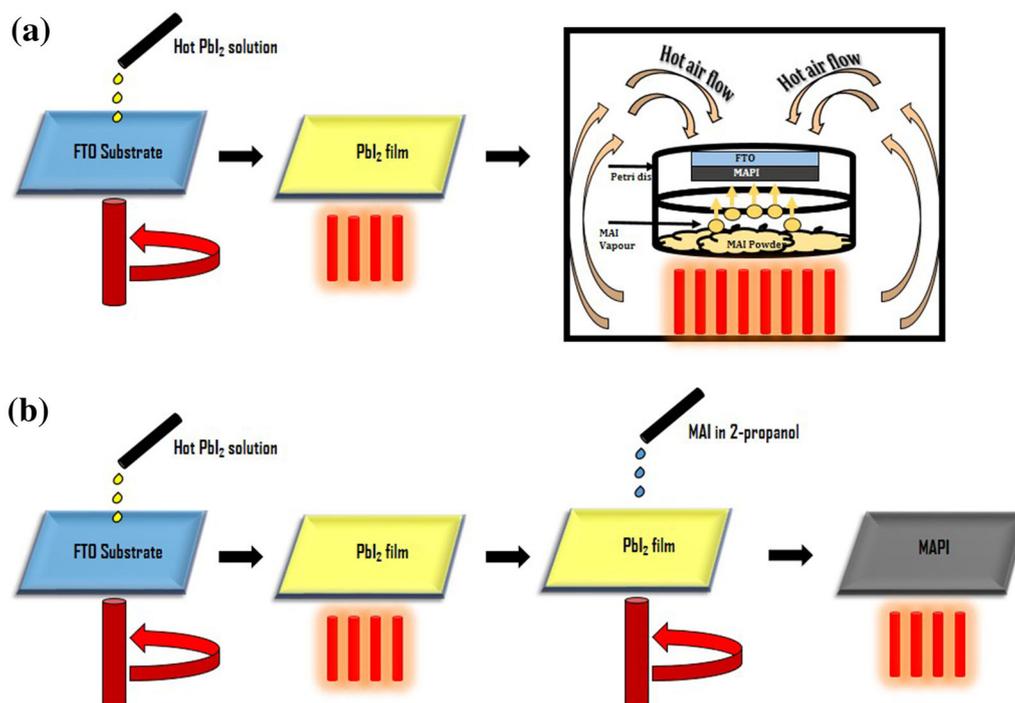


Figure 1. Diagram of the vapour and solution processing setup. (a) Vapour deposition of MAI and (b) solution processing of MAI.

two-step modified vapour deposition technique is proposed to fabricate MAPI thin films under an ambient atmosphere. The modified-vapour deposition is performed by reacting MAI vapour on PbI_2 thin films at 190°C . The *in situ* annealing [3] of the MAPI thin films at the elevated processing temperature eliminates the post-annealing of films after MAI deposition. For comparison, MAPI thin films are also fabricated by the conventional solution process method. Improved crystallinity and better surface morphology are observed for the MAI vapour deposited films. The solution-processed films are not of desirable quality due to the impact of moisture in ambient surrounding.

2. Experimental

For the two-step solution and vapour deposition of MAI, first the PbI_2 precursor solution was prepared by mixing 1 M PbI_2 (Sigma–Aldrich, 99.999%) in 1 ml dimethylformamide (DMF; Alfa-Aesar) and the mixture was stirred at 70°C for 2 h. The hot solution was spin-coated on a pre-cleaned fluorine-doped tin oxide (FTO) coated glass substrate at 3000 rpm for 10 s and annealed at 100°C for 5 min. For solution processing of MAI, 8 mg ml^{-1} freshly prepared MAI [17] solution in 2-propanol was spin-coated on the prepared FTO/ PbI_2 substrate at 1500 rpm for 10 s and annealed at 100°C for 3 min. The setup for the vapour deposition of MAI is shown in figure 1a. For the modified-vapour deposition, first 2 g of the freshly prepared MAI powder was sprinkled

on a Petri dish. Then, the previously prepared FTO/ PbI_2 substrate was placed above the Petri dish with the PbI_2 surface facing the MAI powder. This setup was kept inside a hot air oven at 190°C for 30 min. The MAI powder sublimates to the vapour phase and reacts with the PbI_2 film to form MAPI. It is pertinent to note that from precursor preparation to MAPI crystallization, all the processes were performed under an ambient atmosphere.

3. Results and discussion

3.1 XRD analysis

Figure 2 shows the X-ray diffraction (XRD) patterns of the vapour- and solution-processed MAPI films. The diffraction peaks are matched with the tetragonal ($Pm/3m$) perovskite structure with peaks at $2\theta = 14.02, 15.42, 32.90$ and 38.83° corresponding to the (002), (110), (310) and (200) diffraction planes [18]. The XRD patterns of both the films exhibited no secondary phase, which shows the phase purity of the fabricated MAPI films. An increase in the diffraction peak intensity for the MAPI film fabricated *via* vapour deposition of MAI indicates an enhancement in the crystallinity of the film.

During two-step solution processing, some unreacted compounds may form a residue after thermal annealing due to the incomplete reaction between the reactants during solution deposition. The moisture and O_2 present in the ambient atmosphere also degrades the film quality during thermal

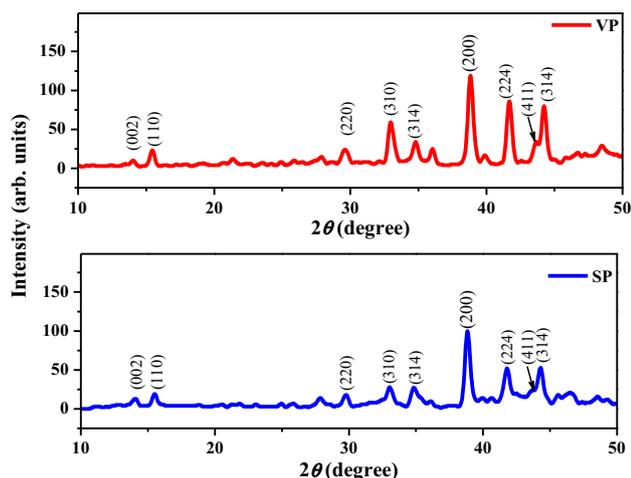


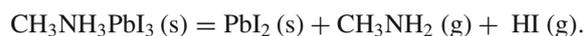
Figure 2. XRD patterns of MAPI thin films fabricated by solution and vapour processing techniques (VP: vapour processed; SP: solution processed).

annealing. Whereas in the case of the vapour deposition process, the organic MAI is deposited in the vapour phase. Thus the residue of any unreacted compound is excluded. Since the vapour processing temperature (190°C) is much higher than the boiling point of DMF (153°C), even any residual solvent in the PbI₂ film is removed. The annealing of the MAPI films after MAI deposition is eliminated in the vapour deposition process, due to the *in situ* annealing during vapour deposition [3]. Importantly, we would like to elucidate that the higher processing temperature (190°C) ensures the absence of moisture in the films at this processing atmosphere, and this might be the reason for the superior quality of the vapour

deposited films, compared to the solution-processed film. This results in the formation of phase pure and highly crystalline MAPI film. These might be the reasons for the enhanced crystallinity of the vapour-processed films.

3.2 Thermal and ambient stability of the films

The possibility of CH₃NH₃PbI₃ to undergo thermal degradation is highly probable at 190°C. The decomposition mechanism of CH₃NH₃PbI₃ in the temperature range of 50–166°C was analysed using Knudsen effusion mass spectrometry [19]. The decomposition path is proposed as follows:



According to the above degradation mechanism, HI and CH₃NH₂ tend to dissociate from CH₃NH₃PbI₃ at higher temperatures (>140°C) [20] transforming CH₃NH₃PbI₃ to PbI₂ in the due course.

However, in our modified-vapour deposition technique, the PbI₂ thin film is treated with MAI vapour at 190°C to induce CH₃NH₃PbI₃ crystallization. The possible dissociation of CH₃NH₂ and HI from the CH₃NH₃PbI₃ film during deposition is concurrently substituted by the incoming CH₃NH₃I vapour. Moreover, after the reaction time of 30 min, the setup is kept undisturbed until it cools to room temperature. Since the entire setup is maintained at the same temperature throughout the process, any possibility of thermal degradation after the vapour deposition is also eliminated. Thus, an equilibrium state is preserved in the material composition during high temperature vapour deposition, leading to the growth of stable CH₃NH₃PbI₃ at 190°C.

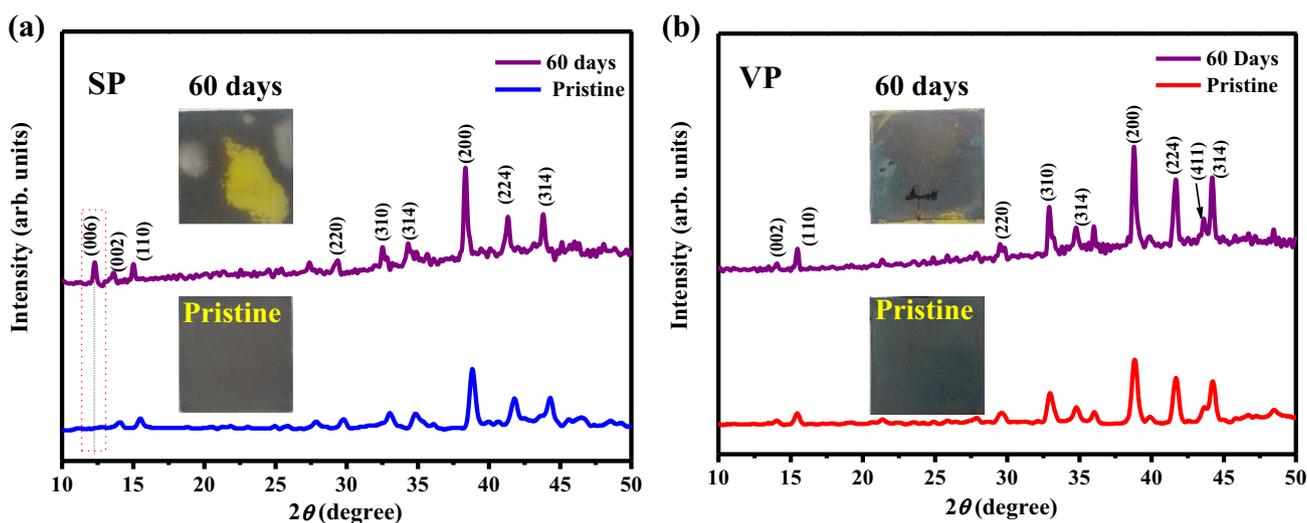


Figure 3. The ambient stability of the solution- and vapour-processed films. (a) New peak at $2\theta = 12.6^\circ$ corresponding to the (006) reflection of PbI₂ is observed for the 60 days aged solution-processed film. (b) No significant change in the XRD pattern of the vapour-processed film can be observed.

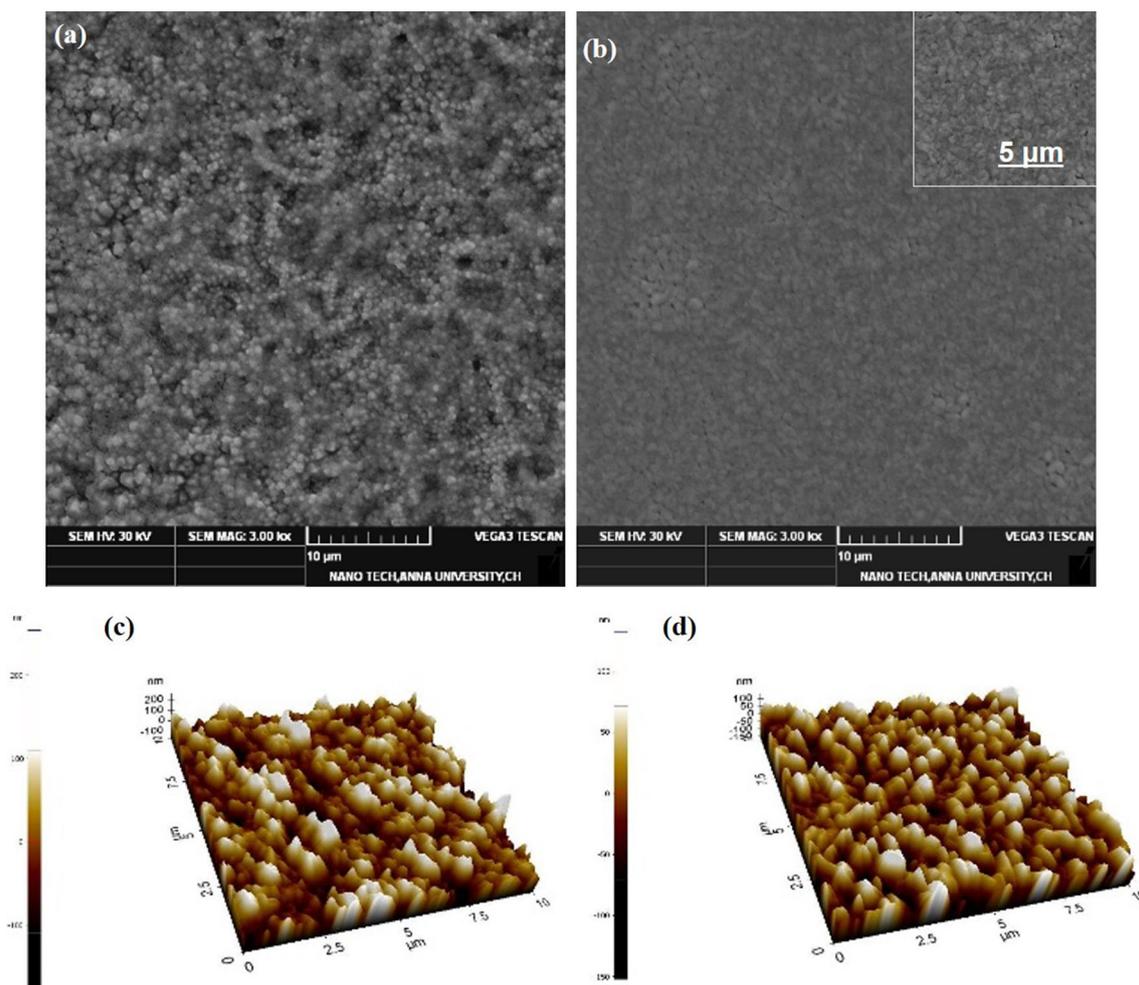


Figure 4. Surface morphology and topography images of solution- and vapour-processed MAPI films. (a, c) solution processed; (b, d) vapour processed.

The stability of both solution and vapour deposited films under ambient conditions was also analysed. The films after fabrication were kept in an open atmosphere, and the XRD pattern was obtained for both films after 60 days and was compared with the XRD patterns of the pristine film. It can be seen that no significant change in the XRD pattern (figure 3b) is observed for the vapour-deposited films, whereas the solution-processed film exhibits a new peak at $2\theta = 12.6^\circ$, which corresponds to the (006) diffraction peak of PbI_2 (figure 3a). Thus, the emergence of a secondary PbI_2 phase can be ascertained by the ambient instability of the solution-processed film. The digital photographs (figure 3, inset) of the solution-processed films also show yellow patches corresponding to the colour of PbI_2 , while the aged-vapour processed film looks similar to the pristine film. The secondary unreacted species present in the solution-processed films might be the reason for the low stability compared to the vapour-processed film.

3.3 Surface morphology and topography

The solution- and vapour-processed MAPI films show totally contrasting surface morphologies. The MAI solution-processed film exhibited a non-uniform, rough surface. There is no uniform grain distribution and the surface appears with a clustered granule-like morphology (figure 4a). The surface roughness was found to be $R_q = 56$ nm from atomic force microscopy (AFM) analysis. The topography image of the solution-processed film complements the scanning electron microscopy (SEM) image with a comparatively rough surface and irregular grain distribution (figure 4c). Generally, the rate of crystallization plays a vital role in the final film quality. A slow rate of crystallization is desired to fabricate good quality MAPI films [21]. The rate of crystallization is controlled by the rate of inter-diffusion of the precursor MAI into the PbI_2 layer [22]. In the MAI solution process, annealing is performed for 3 min duration which leads to a very high rate of crystallization. This rapid crystallization

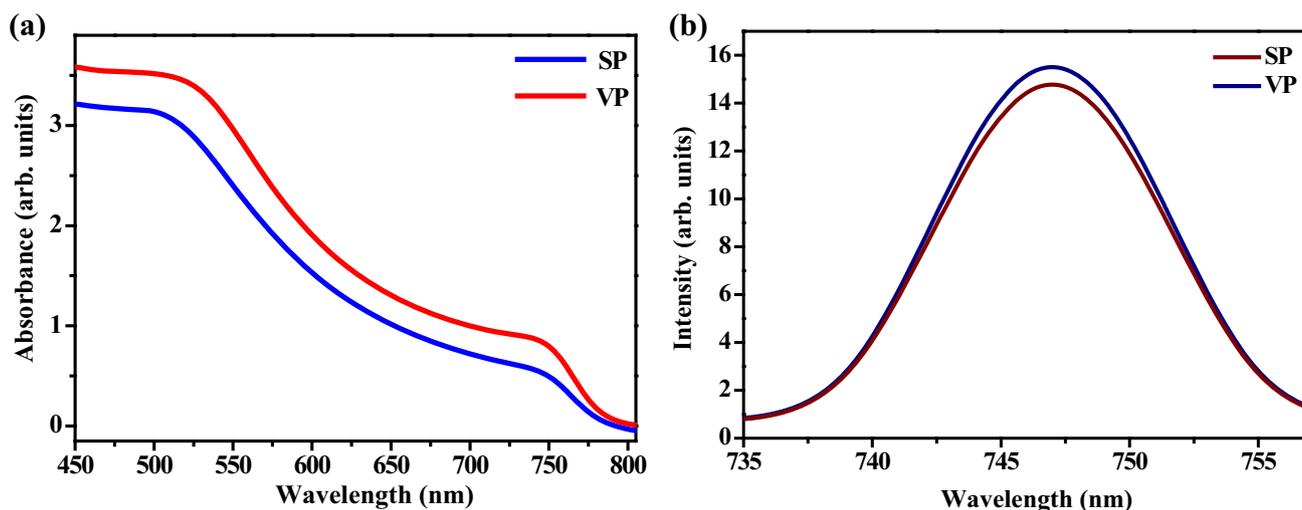


Figure 5. Optical (a) absorption and (b) emission curves of solution- and vapour-processed MAPI films.

of MAPI under ambient air leads to the incomplete reaction between MAI and PbI_2 , and results in the random distribution of grains, ultimately yielding an undesirable surface [23].

Figure 4b shows the SEM image of the vapour-processed film. A planar surface with a uniform grain distribution and superior surface coverage is observed. The surface appears to be planar with a larger grain size compared to the granule-like morphology of the solution-processed film. The AFM results (figure 4d) support the SEM observation displaying a comparatively uniform surface ($R_q = 36$ nm) with a regular grain distribution. It is evident that the vapour phase deposition of MAI greatly influences the surface morphology and crystallinity of the MAPI films. The inhomogeneous distribution of the deposited compounds observed during solution processing is prevented in the vapour deposition of MAI. In vapour deposition, MAI decomposes into CH_3I^- and NH_3^+ [7], and reacts with the PbI_2 thin films to crystallize into $\text{CH}_3\text{NH}_3\text{PbI}_3$. It is to be noted that the moisture free environment created by the modified-vapour deposition technique and the *in situ* annealing [3] has played a critical role in enhancing the quality of the films by this process compared to the solution-processed films.

3.4 Optical properties

The optical properties of the MAPI films were analysed by ultraviolet–visible (UV–Vis) and excited emission spectroscopy. Both the vapour- and solution-processed films show similar absorption curves but the UV–Vis spectra of the vapour-processed film exhibits an increase in the absorption intensity (figure 5). This increase in the absorption concurs with the XRD and SEM results, supporting that the vapour-processed film has better crystalline quality. The emission intensity of the vapour-processed film is slightly higher than

the solution-processed film. It can be interpreted that vapour or solution processing techniques have almost no impact on the characteristic absorption and emission properties. But the enhanced absorbance and emission intensities of the vapour-processed film shall be directly attributed to the improved crystallinity and quality of the MAPI films.

4. Conclusion

A modified two-step deposition technique was utilized by vapour depositing MAI on the PbI_2 films for the fabrication of good quality MAPI thin films under an ambient atmosphere. The properties of the vapour-processed MAPI thin films were compared with the conventional solution-processed films. The structural, morphological and optical properties of the vapour- and solution-processed films were analysed. The XRD results showed that the MAI vapour deposited film had better crystallinity. The surface morphology and topography images showed a planar surface with large grains for the vapour deposited film, while the solution-processed films showed a clustered granule-like morphology. The optical absorption and emission curves also showed an increased absorption and emission for the MAI vapour deposited films, which might be due to the enhanced film quality as observed in the XRD and SEM results. Higher processing temperature of vapour deposition eliminates the effect of moisture that highly impacts the crystallization and final quality of the MAPI film. The slow rate of crystallization during vapour deposition results in better film crystallinity. The results suggest that the modified-vapour deposition of MAI on PbI_2 can yield good quality MAPI films under ambient atmosphere conditions. The effect of different deposition temperatures and complete device fabrication will be analysed as a separate work in future.

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